

# **ISC Silicon NPN Power Transistor**

2SD1555

#### **DESCRIPTION**

- · High Breakdown Voltage-
  - : V<sub>CBO</sub>= 1500V (Min)
- · High Switching Speed
- · Low Saturation Voltage
- · Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

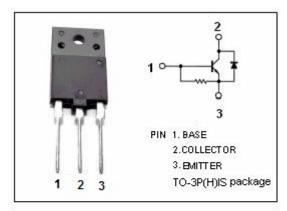
### **APPLICATIONS**

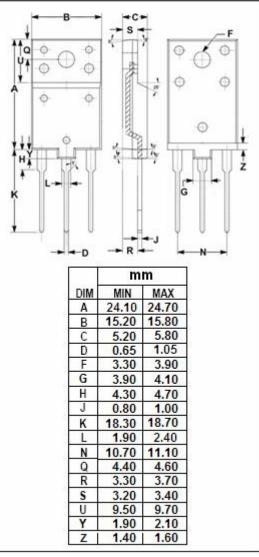


· Designed for color TV horizontal output applications

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	1500	V
V <sub>CEO</sub>	Collector-Emitter Voltage	600	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
lc	Collector Current- Continuous	uous 5	
l <sub>Β</sub>	Base Current- Continuous	2.5	Α
Pc	Collector Power Dissipation @ T <sub>C</sub> =25℃	50	W
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$







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## **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 200mA ; I <sub>C</sub> = 0	5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 0.8A			5.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 0.8A			1.5	V
І <sub>СВО</sub>	Collector Cutoff Current	V <sub>CB</sub> = 500V; I <sub>E</sub> = 0			10	μА
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 5V	8			
V <sub>ECF</sub>	C-E Diode Forward Voltage	I <sub>F</sub> = 5A			2.0	V
f⊤	Current-Gain—Bandwidth Product	Ic= 0.1A; V <sub>CE</sub> = 10V		3		MHz
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f <sub>test</sub> = 1.0MHz		165		pF
t <sub>f</sub>	Fall Time	I <sub>CP</sub> = 4A , I <sub>B1(end)</sub> = 0.8A		0.5	1.0	μS

# **NOTICE:**

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